

# Fast Soft Recovery Rectifier Diode, 20 A



TO-220AC	;
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PRODUCT SUMMARY								
Package	TO-220AC							
I <sub>F(AV)</sub>	20 A							
V <sub>R</sub>	800 V, 1000 V, 1200 V							
V <sub>F</sub> at I <sub>F</sub>	1.31 V							
I <sub>FSM</sub>	355 A							
t <sub>rr</sub>	95 ns							
T <sub>J</sub> max.	150 °C							
Diode variation	Single die							
Snap factor	0.6							

### **FEATURES**

- 150 °C max operating junction temperature
- Low forward voltage drop and short reverse recovery time
- Designed and qualified according to JEDEC-JESD47
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)

### APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

### DESCRIPTION

The VS-20ETF... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	CHARACTERISTICS	VALUES	UNITS							
V <sub>RRM</sub>		800 to 1200	V							
I <sub>F(AV)</sub>	Sinusoidal waveform	20	٨							
I <sub>FSM</sub>		355	A							
t <sub>rr</sub>	1 A, 100 A/µs	95	ns							
V <sub>F</sub>	20 A, T <sub>J</sub> = 25 °C	1.31	V							
TJ	Range	- 40 to 150	°C							

VOLTAGE RATINGS										
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA							
VS-20ETF08PbF, VS-20ETF08-M3	800	900								
VS-20ETF10PbF, VS-20ETF10-M3	1000	1100	6							
VS-20ETF12PbF, VS-20ETF12-M3	1200	1300								

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum average forward current	I <sub>F(AV)</sub>	$T_C = 97$ °C, 180° conduction half sine wave	20						
Maximum peak one cycle non-repetitive surge current		10 ms sine pulse, rated V <sub>RRM</sub> applied	А						
	IFSM	10 ms sine pulse, no voltage reapplied	355	1					
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	450	A <sup>2</sup> s					
	1-1	10 ms sine pulse, no voltage reapplied	635	- A <sup>2</sup> S					
Maximum I <sup>2</sup> √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	6350	A²√s					

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1





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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS					
Maximum forward voltage drop	V <sub>FM</sub>	20 A, T <sub>J</sub> = 25 °C	1.31	V					
Forward slope resistance	r <sub>t</sub>	T <sub>J</sub> = 150 °C	11.88	mΩ					
Threshold voltage	V <sub>F(TO)</sub>	1j = 150°C	0.93	V					
Maximum reverse leakage current	I	T <sub>J</sub> = 25 °C	25 °C		mA				
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	V <sub>R</sub> = Rated V <sub>RRM</sub>	6	ША				

RECOVERY CHARACTERISTICS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Reverse recovery time	t <sub>rr</sub>	l <sub>F</sub> at 20 Apk	400	ns	I <sub>FM</sub> t				
Reverse recovery current	I <sub>rr</sub>	25 A/μs	6.1	А					
Reverse recovery charge	Q <sub>rr</sub>	25 °C	1.7	μC					
Snap factor	S	Typical	0.6		I I <sub>RM(REC)</sub>				

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and sto temperature range	orage	T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 150	°C				
Maximum thermal resistar junction to case	nce,	R <sub>thJC</sub>	DC operation	0.9					
Maximum thermal resistar junction to ambient	ice,	R <sub>thJA</sub>		62	°C/W				
Typical thermal resistance case to heatsink	à,	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.5	1				
Approvimate weight				2	g				
Approximate weight				0.07	oz.				
Mounting torque	minimum			6 (5)	kgf ⋅ cm				
Mounting torque	maximum			12 (10)	(lbf ⋅ in)				
Marking device			Case style TO-220AC	20E 20E 20E	rF10				

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# VS-20ETF..PbF Series, VS-20ETF..-M3 Series

**Vishay Semiconductors** 

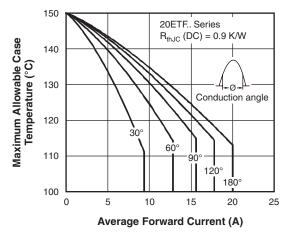


Fig. 1 - Current Rating Characteristics

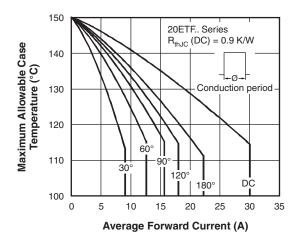
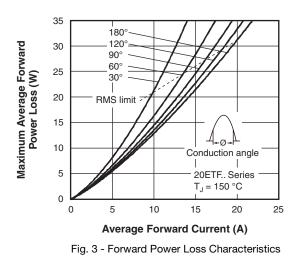


Fig. 2 - Current Rating Characteristics



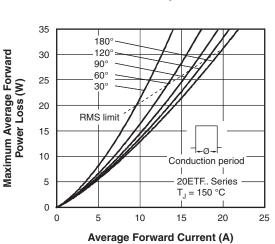
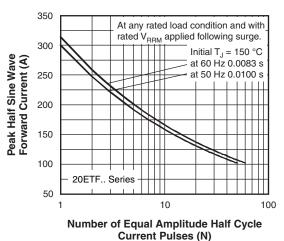
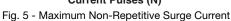


Fig. 4 - Forward Power Loss Characteristics





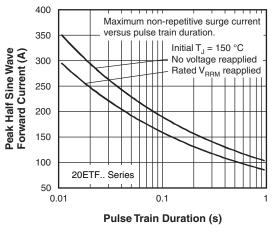


Fig. 6 - Maximum Non-Repetitive Surge Current

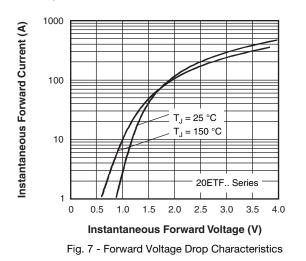
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3

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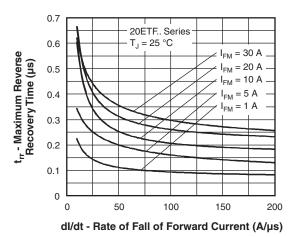


Fig. 8 - Recovery Time Characteristics,  $T_J = 25 \degree C$ 

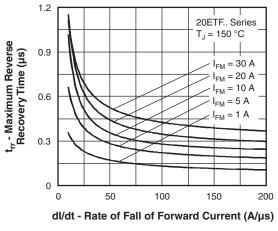


Fig. 9 - Recovery Time Characteristics,  $T_J$  = 150  $^\circ C$ 

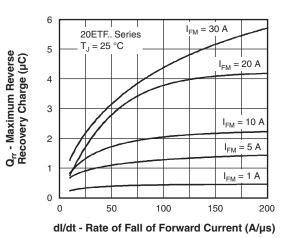
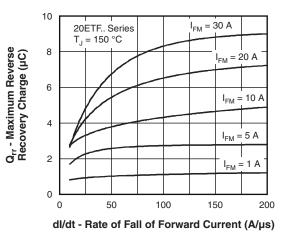
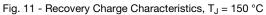
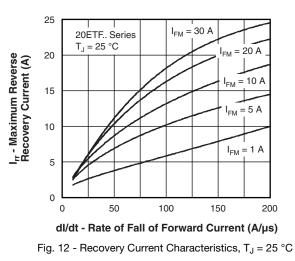


Fig. 10 - Recovery Charge Characteristics,  $T_J = 25 \ ^{\circ}C$ 







Revision: 26-Oct-11

4

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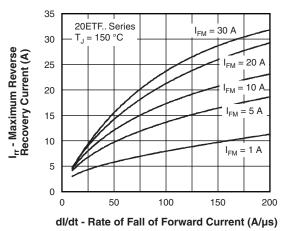


Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C

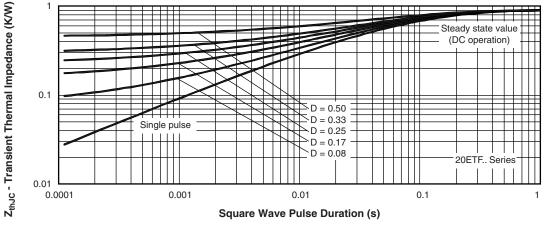


Fig. 14 - Thermal Impedance  $Z_{thJC}$  Characteristics



## **ORDERING INFORMATION TABLE**

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			_	_	_		
Device code	VS-	20	E	Т	F	12	PbF
	(1)	(2)	(3)	(4)	(5)	(6)	(7)
	1 -	Visł	nay Sem	niconduc	ctors pro	oduct	
	2 -	Cur	rent rati	ng (20 =	= 20 A)		
	3 -	Circ	uit conf	iguratior	า:		
		E =	Single of	diode			
	4 -	Pac	kage:				
	_	T =	TO-220	AC			
	5 -	Тур	e of silio	con:			
	_			ft recove	ery recti		08 = 80
	6 -		age rati	-			10 = 100 12 = 120
	7 -			ntal digit			
		• Pl	oF = Lea	ad (Pb)-	free and	RoHS	complia
		• -N	13 = Hal	ogen-fre	e, RoH	S comp	oliant, ar

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-20ETF08PbF	50	1000	Antistatic plastic tube							
VS-20ETF08-M3	50	1000	Antistatic plastic tube							
VS-20ETF10PbF	50	1000	Antistatic plastic tube							
VS-20ETF10-M3	50	1000	Antistatic plastic tube							
VS-20ETF12PbF	50	1000	Antistatic plastic tube							
VS-20ETF12-M3	50	1000	Antistatic plastic tube							

LINKS TO RELATED DOCUMENTS							
Dimensions		www.vishay.com/doc?95221					
Part marking information	TO-220AC PbF	www.vishay.com/doc?95224					
	TO-220AC -M3	www.vishay.com/doc?95068					

6

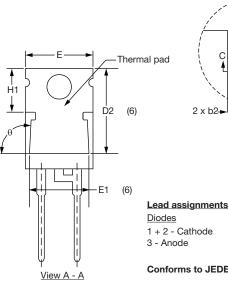


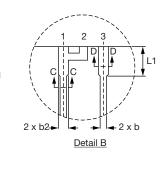
**TO-220AC** 

plane

### **DIMENSIONS** in millimeters and inches









**Diodes** 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

⊕ 0.015 **()** BA()

SYMBOL	MILLIN	IETERS	INC	HES	NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183			E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055			E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115			е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040			e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4		H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068			L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4		L1	3.32	3.82	0.131	0.150	2
с	0.36	0.61	0.014	0.024			L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4		L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3		ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355			Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6		θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6							

Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

- <sup>(2)</sup> Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- <sup>(4)</sup> Dimension b1, b3 and c1 apply to base metal only
- <sup>(5)</sup> Controlling dimension: inches
- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2 and E1
- <sup>(7)</sup> Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- <sup>(8)</sup> Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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